

MEDIUM POWER AMPLIFIER

Typical Applications

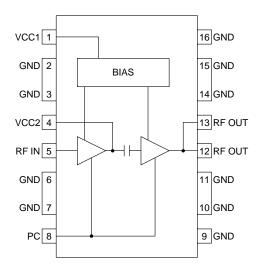
- 900MHz ISM Band Applications
- 400MHz Industrial Radios
- Driver for Higher Power Applications
- Portable Battery-Powered Equipment
- Commercial and Consumer Systems
- Base Station Equipment

Product Description

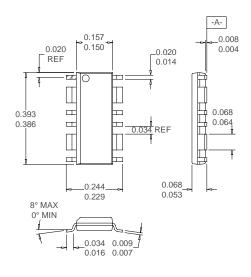
The RF2104 is a medium power amplifier IC. The device is manufactured on a low cost Silicon process, and has been designed for use as the final RF amplifier in UHF radio transmitters operating between 400MHz and 1000MHz. It may also be used as a driver amplifier in higher power applications. The device is packaged in a plastic quad-batwing 16-lead package, and is self-contained with the exception of the output matching network, power supply feed line, and bypass capacitors. It produces an output power level of up to 500mW (CW) at 3.6V. The device can be used in 3 cell battery applications. The maximum CW output at 3.6V is +27dBm. The unit has a total gain of 26dB, depending upon the output matching network.

Optimum Technology Matching® Applied

✓ Si BJT ☐ GaAs HBT ☐ GaAs MESFET☐ Si Bi-CMOS ☐ SiGe HBT ☐ Si CMOS



Functional Block Diagram



Package Style: CJ2BAT0

Features

- 400MHz to 1000MHz Operation
- Up to 500mW CW Output Power
- 26dB Small Signal Gain
- 40dB Gain Control Range
- Single 2.7V to 3.6V Supply
- 40% Efficiency

Ordering Information

RF2104 Medium Power Amplifier

RF2104 PCBA-L Fully Assembled Evaluation Board (830 MHz) RF2104 PCBA-H Fully Assembled Evaluation Board (915 MHz)

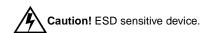
RF Micro Devices, Inc. 7625 Thorndike Road Greensboro, NC 27409, USA Tel (336) 664 1233 Fax (336) 664 0454 http://www.rfmd.com

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RF2104

Absolute Maximum Ratings

Parameter	Rating	Unit
Supply Voltage	-0.5 to +6.0	V_{DC}
Gain Control Voltage (V _{PC})	-0.5 to +3.0	V
DC Supply Current	500	mA
Input RF Power	+12	dBm
Output Load VSWR	20:1	
Operating Ambient Temperature	-40 to +85	°C
Storage Temperature	-40 to +150	℃



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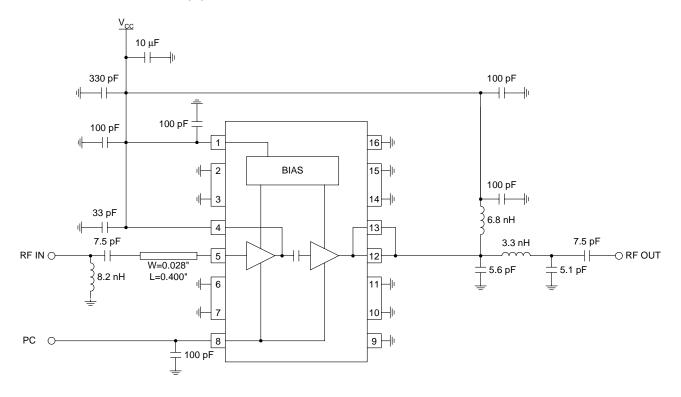
Parameter	Specification		Unit	Condition		
Farameter	Min.	Тур.	Max.	Offic	Condition	
Overall					T=25°C, V _{CC} =3.6V, V _{PC} =2.5V,	
					Z_{LOAD} =10 Ω , P_{IN} =+6dBm, Freq=850MHz	
Frequency Range		400 to 1000		MHz		
Bandwidth		150		MHz	With fixed matching network	
Maximum Output Power		+27		dBm	V_{CC} =3.6V, P_{IN} =+6dBm	
Maximum Output Power		+27		dBm	V_{CC} =3.0V, P_{IN} =+6dBm	
Output Third Order Intercept		+36		dBm	V _{CC} =3.6V	
Power Added Efficiency		40		%	V_{CC} =3.6V, P_{OUT} =+27dBm, P_{IN} =+6dBm	
Small Signal Gain	24	25	28	dB	V_{CC} =3.6V, V_{PC} =+2.5V, Freq=850MHz	
Gain Control Range		35	40	dB	V _{PC} =0V to 2.5V	
Second Harmonic		-50		dBc	Without external second harmonic trap	
Third Harmonic		-50		dBc		
Noise Figure		5.5	7.0	dB		
Input Impedance		50		Ω		
Input Return Loss		-20	-15	dB	With external matching network; see application schematic	
Input Return Loss		-10		dB	Without external matching network	
Output Impedance		50		Ω	Not matched for maximum output power	
Output Return Loss		-13		dB	Without external matching network	
Load Impedance		5+j0		Ω	Load Impedance for Optimal Power Match	
Power Supply						
Power Supply Voltage		2.7 to 3.6		V		
Power Supply Idle Current		250	300	mA	$V_{PC}=2.5V$	
Total "OFF" Current Drain		1	10	μΑ	V_{PC} <0.25 V_{DC} ; No RF input power	
Total "OFF" Current Drain		4		mA	V_{PC} <0.25 V_{DC} ; P_{IN} =+6dBm	
Current into PC pin			1	mA	V _{PC} =2.5V	
Current into PC pin		0		μΑ	V _{PC} =0V	
Turn-on Time		<100		ns	V_{PC} =0V to V_{PC} =+2.5 V_{DC}	

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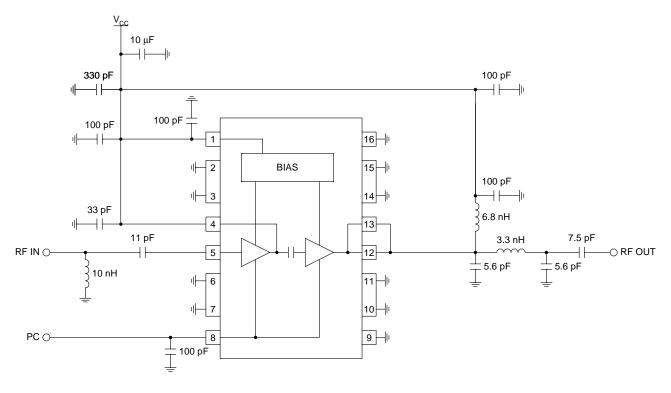
Pin	Function	Description	Interface Schematic
1	VCC1	Power supply for the bias circuits. This pin draws current proportional to V_{PC} . When V_{PC} is 2.5 V the maximum current is about 30 mA. When V_{PC} goes down to 0 V the current also goes down to 0 mA.	VCC1 PC O To Bias Stages 40 Ω To Bias
2	GND	Ground connection. For best performance, keep traces physically short and connect immediately to ground plane. A via hole under each ground pin to the ground plane is recommended.	
3	GND	Same as pin 2.	
4	VCC2	Power supply for the driver stage and interstage matching. An external decoupling capacitor is required. The electrical length between the pin and this capacitor affects the gain. See the application schematic for recommended line length for optimum gain. For operation at frequencies below 600MHz a series inductor is required.	VCC2 RF IN OFFICE Bias Stages
5	RF IN	50Ω RF input. DC voltages are present at this pin, and an external blocking capacitor is required when connecting this pin to a DC path to ground. For optimum impedance matching, a shunt inductor to ground is recommended; see the application schematic for details.	See pin 4 schematic.
6	GND	Same as pin 2.	
7	GND	Same as pin 2.	
8	PC	Power control pin. A DC voltage between 0V and 3.0V can be applied to control the gain. When no gain control is required this pin should be connected to a fixed voltage between 2.5V and 3.0V. This pin draws some current proportional to V_{PC} . When V_{PC} is 2.5V the maximum current into this pin is about 1 mA.	See pin 1 schematic.
9	GND	Same as pin 2.	
10	GND	Same as pin 2.	
11	GND	Same as pin 2.	
12	RF OUT	RF output. The power supply for the output stage also needs to be supplied to this pin through the external matching circuit. The load impedance to this pin should be $5+j0\Omega$ for maximum output power.	RF OUT From Bias = Stages
13	RF OUT	Same as pin 12.	See pin 12 schematic.
14	GND	Same as pin 2.	
15	GND	Same as pin 2.	
16	GND	Same as pin 2.	

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Application Schematic - 915MHz

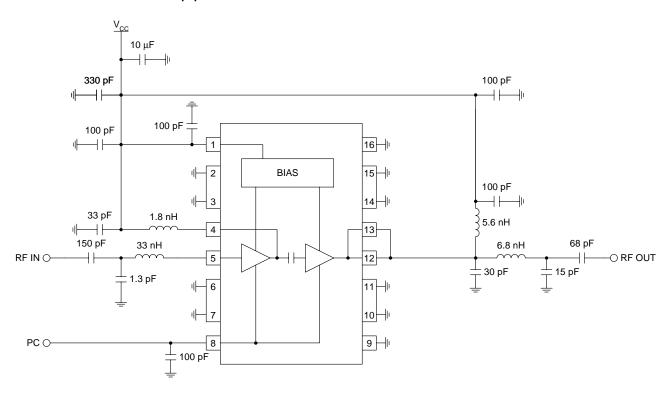


Application Schematic - 830MHz



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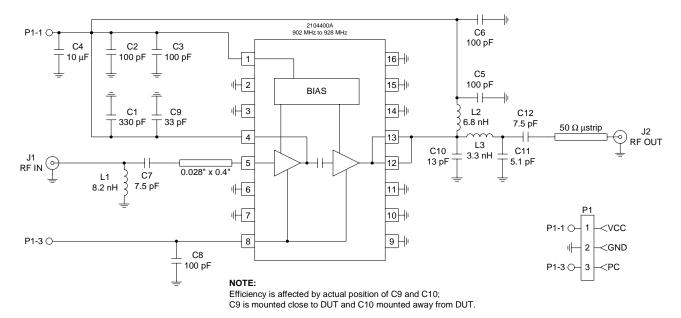
Application Schematic - 420MHz



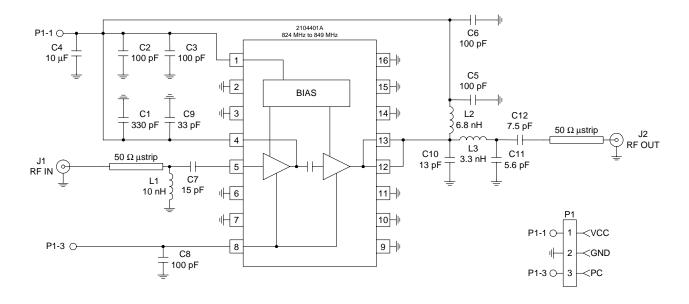
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Evaluation Board Schematic - 915MHz

(Download Bill of Materials from www.rfmd.com.)

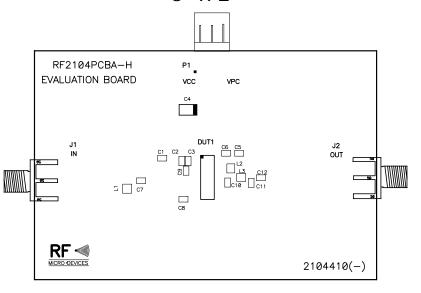


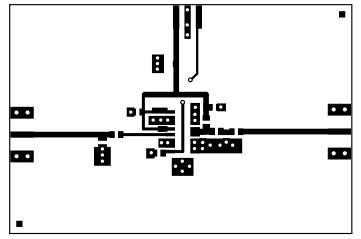
Evaluation Board Schematic - 830MHz

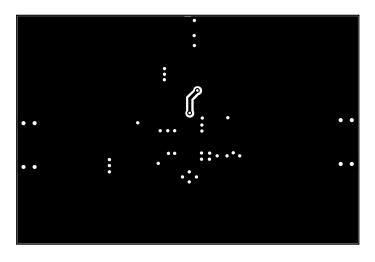


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Evaluation Board Layout - 915MHz 3" x 2"

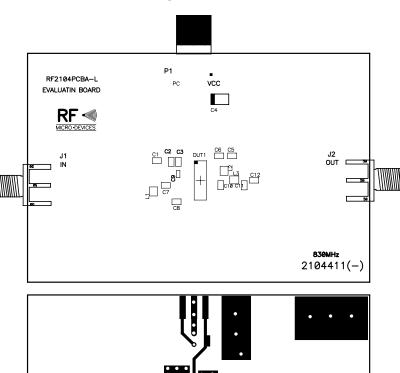


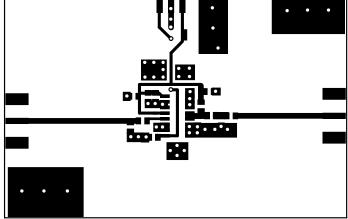


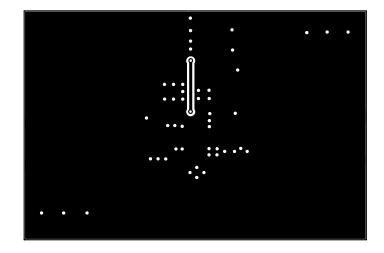


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Evaluation Board Layout - 830MHz 3" x 2"







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